

IPM Photocoupler

Product Description

The EMD2A480 fast speed photocoupler contains a LED and photo detector with built-in Schmitt trigger to provide logic -compatible waveforms, eliminating the need for additional wave shaping. The totem pole output eliminates the need for a pull up resistor and allows for direct drive Intelligent Power Module or gate drive. Minimized propagation delay difference between devices makes these optocouplers excellent solutions for improving inverter efficiency through reduced switching dead time.

Applications

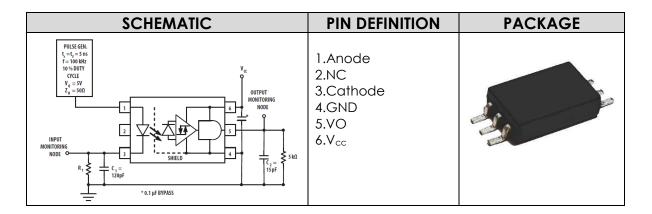
- IPM Interface Isolation
- Isolated IGBT/MOSFET Gate Drive
- AC and Brushless DC Motor Drives
- Industrial Inverters
- General Digital Isolation

Features

- Totem pole output
- Truth Table Guaranteed: VCC from 4.5V to 30V
- Performance Specified for Common IPM Applications Over Industrial Temperature Range.
- Short Maximum Propagation Delays
- Minimized Pulse Width Distortion (PWD)
- Very High Common Mode Rejection (CMR)
- Hysteresis
- Data rate: 5Mbps (typ.)

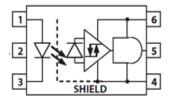
Safety approved

- UL1577 recognized with 3750 Vrms for 1 minute for EMD2A480-SK and 5000 Vrms for 1 minute for EMD2A480-SL Certificate No. E529603
- IEC/EN/DIN EN 60747-5-5 Approved
 V_{IORM} = 891 Vpeak for EMD2A480-SK
 V_{IORM} = 1140 Vpeak for EMD2A480-SL
 Certificate No. 40055846
- CQC approved: GB4943.1-2011
 Certificate No. CQC22001358589





Connection Diagram



Order Information

EMD2A48	EMD2A480-00S###%FR1				
00	Internal control Code				
S###	SK06: LSOP-6 Package 7mm clearance				
	SL06: LSOP-6 Package 8mm clearance				
%	E: RoHS & Halogen free package with VDE				
	N: RoHS & Halogen free package				
F	-40 to 110°C temperature rating				
R1	Packing in Tape & Reel				

Order, Mark & Packing Information

Package	Product ID		Mark	Packing
	EMD2A480-00SK06EFR1 EMD2A480-00SL06EFR1	EYYWW 480 HV	E : ESMT YY : Date code (Year) WW : Date code (Week)	Tape &
LSOP-6	EMD2A480-00SK06NFR1 EMD2A480-00SL06NFR1	EYYWW 480 H	480 : Part Number H : Internal Tracking Code V : VDE Option	Reel 3Kpcs

Description	Symbol	EMD2480-SK	EMD2A480-SL	Unit
Climatic Classification		55/100/21	55/100/21	
Pollution Degree (DIN VDE 0110/1.89)		2	2	
Maximum Working Insulation Voltage	VIORM	891	1140	Vpeak
Input to Output Test Voltage, Method b (Note 1)				
VIORM X 1.875=Vpr, 100% Production Test	Vpr	1671	2137	Vpeak
With tm=1sec, Partial discharge < 5pC				
Input to Output Test Voltage, Method a (Note 1)				
VIORM X 1.6=Vpr, 100% Production Test	Vpr	1426	1824	Vpeak
With tm=10sec, Partial discharge < 5pC				
Highest Allowable Overvoltage		(000	0000	
(Transient Overvoltage t _{ini} = 60sec)	VIOTM	6000	8000	Vpeak
Safety-limiting values – maximum v	alues allowed	d in the event of	a failure	
Case Temperature	Ts	175	175	°C
Input Current	IS, INPUT	150	150	mA
Output Power	Ps, output	600	600	mW
Insulation Resistance at TS, V_{10} = 500 V	Rs	>109	>109	Ω

IEC/EN/DIN EN 60747-5-5 Insulation Characteristics

Note 1 : Refer to the optocoupler section of the Isolation and Control Components Designer's Catalog, under Product Safety Regulations section, (IEC/EN/DIN EN 60747-5-5) for a detailed description of Method a and Method b partial discharge test profiles.

These optocouplers are suitable for "safe electrical isolation" only within the safety limit data. Maintenance of the safety data shall be ensured by means of protective circuits. Surface mount classification is Class A accordance with CECC 00802.

Insulation and Safety-Related Specifications

Parameter	Symbol	EMD2A		Unit	Conditions
raiamelei	Symbol	480-SK			Conditions
Minimum External Air Gap (External	1 (101)	7.0	8.0		Measured from input terminals to output
Clearance)	L(101)	7.0	0.0	mm	terminals, shortest distance through air.
Minimum External Tracking (External Creepage)	L(102)	8.0	8.0		Measured from input terminals to output terminals, shortest distance path along body.
Tracking Resistance (Comparative Tracking Index)	CTI	>175	>175	V	DIN IEC 112/VDE 0303 Part 1.



Truth Table

LED	Vcc-Vss (Turn-ON)
LED	OUT
ON	Н
OFF	L

Note 2: A 0.1µF bypass capacitor must be connected between Pin 4 and 6.

Absolute Maximum Ratings (Ta = 25°C unless otherwise specified)

Parameter	Symbol	Min	Max	Unit			
Storage Temperature	Tstg	-55	125	°C			
Operating Temperature	Topr	-40	110	°C			
Output IC Junction Temperature	TJ	-	125	°C			
Average Forward Input Current	IF	-	20	mA			
Reverse Input Voltage	VR	-	5	V			
Output Collector Current	IO		50	mA			
Supply Voltage	VCC	0	35	V			
Output Collector Voltage	VO	-0.5	Vcc	V			
Total Package Power Dissipation	PT	-	145	mW			
Lead Solder Temperature	Tsol	-	260	°C			

Note 3: A ceramic capacitor (0.1 µF) should be connected between pin 6 and pin 4 to stabilize the operation of a high gain linear amplifier. Otherwise, this Photocoupler may not switch properly. The bypass capacitor should be placed within 1 cm of each pin.

Recommended Operation Condition

Parameter	Symbol	Min	Max	Unit
Operating Temperature	T _A	-40	110	°C
Supply Voltage	Vcc	4.5	30	V
Input Current (ON) (Note 4)	If(ON)	1.6	5	mA
Input Voltage (OFF) (Note 5)	V _{F(OFF)}		0.8	V

Note 4: Detector requires a VCC of 4.5 V or higher for stable operation as output might be unstable if VCC is lower than 4.5 V. Be sure to check the power ON/OFF operation other than the supply current.

Note 5: The initial switching threshold is 1.6 mA or less. It is recommended that 2.2 mA be used to permit at least a 20% LED degradation guard band.

Electrical Characteristics

All Typical values at $T_A = 25^{\circ}$ C, unless otherwise specified; all minimum and maximum specifications are at recommended operating condition.

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
		Inpu	ut Chara	cteristic	s	
Input Forward Voltage	VF	1.6	2.0	2.4	V	IF=10mA
Input Forward Voltage Temperature Coefficient	ΔVF/ ΔΤ	-	-1.237	-	mV/°C	IF=10mA
Input Reverse Voltage	BVR	5	-	-	~	IR = 10µA
Input Threshold Current (Low to High)	IFLH	-	0.2	1.5	mA	VCC = 30 V, VO> 5V
Input Threshold Voltage (High to Low)	VFHL	0.8	-	-	V	VCC = 30 V, VO< 5V
Input Capacitance (Note 6)	CIN	-	60	-	pF	f = 1 MHz, VF = 0 V
		Outp	out Chara	acteristic	CS .	
High Level Supply Current	ICCH	-	-	3.0	mA	VCC = 5.5 V, IF = 5 mA, IO = 0 mA
High Level Supply Colleni			1.9	3.0		VCC = 30 V, IF = 5 mA, IO = 0 mA
Low Level Supply Current	ICCL	-	-	3.0	mA	VCC = 5.5 V, VF = 0V, IO = 0 mA
	ICCL		2.0	3.0		VCC = 30 V, VF = 0 V, IO = 0 mA
High level output current		-	-	-100		VCC = 5.5V, IF = 5mA, VO = GND
(Note 7)	IOH	-	-	-200	mA	VCC = 20V, IF = 5mA, VO = GND
Low level output current		100	-	-		VO =VCC = 5.5V, VF = 0V
(Note 7)	IOL	200	-	-	mA	VO =VCC = 20V, VF = 0V
High level output voltage	VOH	VCC- 0.5	VCC- 0.04	-	V	IOL = -6.5mA
Low level output voltage	VOL	-	0.09	0.5	V	IOL = 6.5mA

Note 6: Input capacitance is measured between pin 1 and pin 3.

Note 7: Duration of output short circuit time should not exceed 10 µs.

Switching Specification

All Typical values at TA = 25°C, unless otherwise specified; all minimum and maximum specifications are at recommended operating condition.

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Condition
Propagation Delay Time toHigh Output Level (Note 8)	† _{PLH}	-	110	220		
Propagation Delay Time toLow Output Level (Note 8)	t _{PHL}	-	90	220		f = 10kHz.
Pulse Width Distortion (Note 9)	PWD	-	20	120	ns	Duty Cycle = 50%
Propagation Delay Difference Between Any Two Parts (Note 10)	PDD (tphl - tplh)	-200	-	+200		$V_{CC} = 30V$
Output Rise Time (10 to 90%)	tr	-	6	-		
Output Fall Time (90 to 10%)	t _f	-	7	-		
Common mode transient immunity at high level output (Note 11)	CMH	20	-	-	kV/µs	I _F =4.0 mA V _{CC} = 5V, T _A = 25 °C, V _{CM} = 1.5KV
Common mode transient immunity at low level output (Note 11)	CML	20	-	-	kV/µs	V _F =0V V _{CC} = 5V, T _A = 25 °C, V _{CM} = 1.5KV

Note 8: The tPLH propagation delay is measured from the 50% point on the leading edge of the input pulse to the 1.3 V point on the leading edge of the output pulse. The tPHL propagation delay is measured from the 50% point on the trailing edge of the input pulse to the 1.3 V point on the trailing edge of the output pulse.

Note 9: Pulse Width Distortion (PWD) is defined as | tPHL - tPLH | for any given device.

Note 10: The difference of tPLH and tPHL between any two devices under the same test condition.

Note 11: CMH is the maximum slew rate of the common mode voltage that can be sustained with the output voltage in the logic high state, VO > 2.0 V. CML is the maximum slew rate of the common mode voltage that can be sustained with the output voltage in the logic low state, VO < 0.8 V. Note: Equal value split resistors (Rin/2) must be used at both ends of the LED.

Isolation characteristic

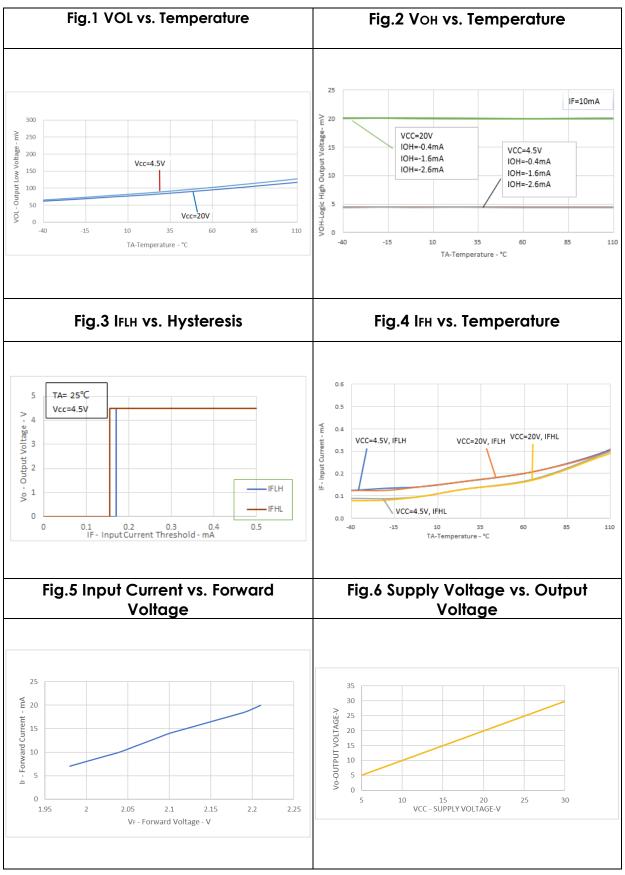
All Typical values at $T_A = 25^{\circ}$ C and $V_{CC} - V_{SS} = 30$ V, unless otherwise specified; all minimum and maximum specifications are at recommended operating condition.

Parameter	Symbol	Device	Min.	Тур.	Max.	Unit	Test Condition
Withstand Insulation Test Voltage	VISO	EMD2A480-SK	5000	_	_	V	RH ≤ 40%-60%,
(Note 12, 13)	130	EMD2A480-SL	0000			·	t = 1 min, T _A = 25 °C
Input-Output Resistance (Note 12)	R _{I-O}	-	-	10 ¹²	-	Ω	V _{I-0} = 500V DC

Note 12: Device is considered a two terminal device: pins 1, 2, 3 are shorted together and pins 4, 5, 6 are shorted together.

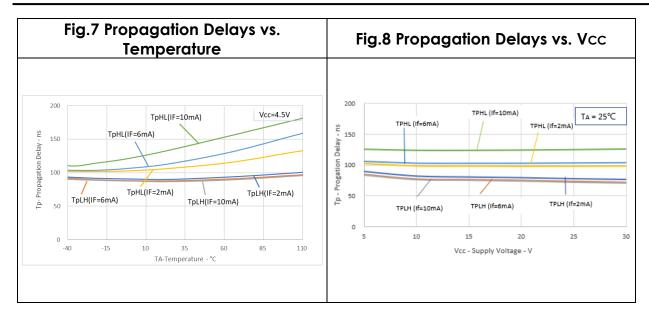
Note 13: According to UL1577, each photo coupler is tested by applying an insulation test voltage 6000VRMS for one second.

Typical Performance Curves & Test Circuits



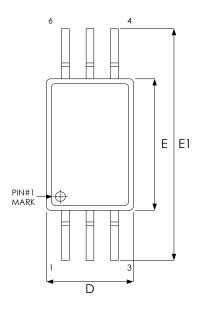
Elite Semiconductor Microelectronics Technology Inc.







Package Outline Drawing L-SOP 6L (277mil, 7mm clearance)

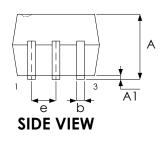


TOP VIEW

SIDE VIEW

C

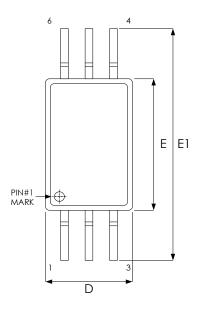
L



Symbol	Dimension in mm				
Symbol	Min.	Max.			
А	1.70	2.30			
A1	0.10	0.30			
b	0.30	0.50			
С	0.20	0.30			
D	4.20	4.80			
Е	6.51	7.11			
E1	9.40	10.00			
е	1.27 BSC				
L	0.70	1.20			



Package Outline Drawing L-SOP 6L (277mil, 8mm clearance)

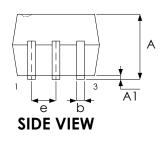


TOP VIEW

SIDE VIEW

C

L



Symbol	Dimension in mm				
Symbol	Min.	Max.			
А	1.70	2.30			
A1	0.10	0.30			
b	0.30	0.50			
С	0.20	0.30			
D	4.20	4.80			
Е	6.51	7.11			
E1	11.20	11.80			
е	1.27 BSC				
L	0.50	1.00			



Revision History

Revision	Date	Description
0.1	2023.02.17	Preliminary version
0.2	2023.08.24	Update: Insulation Characteristics(Page3) AMR unit (Page4) Note7 (Page5) CML Test condition (Page6)
1.0	2024.03.05	1.Revise IOH/IOL spec 2.Update POD 3. Remove "preliminary" to V1.0

Important Notice

All rights reserved.

No part of this document may be reproduced or duplicated in any form or by any means without the prior permission of ESMT.

The contents contained in this document are believed to be accurate at the time of publication. ESMT assumes no responsibility for any error in this document, and reserves the right to change the products or specification in this document without notice.

The information contained herein is presented only as a guide or examples for the application of our products. No responsibility is assumed by ESMT for any infringement of patents, copyrights, or other intellectual property rights of third parties which may result from its use. No license, either express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of ESMT or others.

Any semiconductor devices may have inherently a certain rate of failure. To minimize risks associated with customer's application, adequate design and operating safeguards against injury, damage, or loss from such failure, should be provided by the customer when making application designs.

ESMT's products are not authorized for use in critical applications such as, but not limited to, life support devices or system, where failure or abnormal operation may directly affect human lives or cause physical injury or property damage. If products described here are to be used for such kinds of application, purchaser must do its own quality assurance testing appropriate to such applications.